

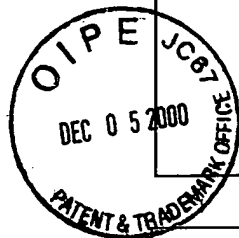
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PTO-1449 (Modified)

ATTY. DOCKET NO.  
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09/514,872U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICEAPPLICANT(S)  
FARMWALD ET AL.INFORMATION DISCLOSURE  
STATEMENT  
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FEBRUARY 28, 2000GROUP ART UNIT  
2781  
2181

## U.S. PATENT DOCUMENTS

EXAMINER INITIALS	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE
Per [initials]	4,633,735	05/05/87	Novak, et. al	—	—	
[initials]	5,684,753	11/04/97	Hashimoto, et al	—	—	
Per [initials]	4,322,635	03/30/80	Redwine	—	—	
[initials]	5,006,982	04/09/91	Ebersole et al.	—	—	
[initials]	4,636,986	01/13/87	Pinkham	—	—	

## FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION YES/NO

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

[initials]	Ikeda, Hiroaki et al., "100 MHz Serial Access Architecture for 4Md Field Memory," Symposium of VLSI Circuits, Digest of Technical Papers, pp. 11-12 (Jun. 1990)
[initials]	Takasugi, A. et al., "A DATA TRANSFER ARCHITECTURE FOR FAST MULTI-BIT SERIAL ACCESS MODE DRAM", 11TH European Solid State Circuits Conference, Toulouse France pp. 161-165 (Sep. 1985)
[initials]	Ray Pinkham et al., "A 128Kx8 70-MHz Multiport Video RAM with Auto Register Reload and 8x4 WRITE Feature," IEEE Journal of Solid State Circuits, vol. 23, no. 3, pp. 1133-1139 (Oct. 1988)
[initials]	Graham, Andy et al., "Pipelined static RAM endows cache memories with 1-ns speed", Electronic Design pp. 157-170 (Dec. 1984)
[initials]	Robert J. Lodi et al., "Chip and System Characteristics of a 2048-Bit MNOS-BORAM LSI Circuit," IEEE International Solid-State Circuits Conference, (Feb. 1976)
[initials]	Pinkham, Raymond, "A High Speed Dual Port Memory with Simultaneous Serial and Random Mode Access for Video Applications," IEEE Journal of Solid-State Circuits, Vol. SC-19, No. 6, pp. 999-1007 (Dec. 1984)
[initials]	Ishimoto, S. et al., "A 256K Dual Port Memory," ISSCC Digest of Technical Papers, p. 38-39 (Feb. 1985)

EXAMINER

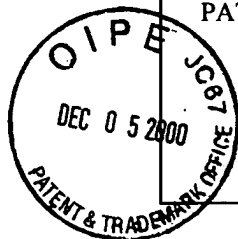
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PTO-1449 (Modified)  U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE  INFORMATION DISCLOSURE STATEMENT BY APPLICANT	ATTY. DOCKET NO. RA001C10	SERIAL NUMBER 09/514,872
	APPLICANT(S) FARMWALD ET AL.	
	FILING DATE FEBRUARY 28, 2000	GROUP ART UNIT <del>2781</del> 2181



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MA	Tomoji Takada et al., "A Video Codec LSI for High-Definition TV Systems with One-Transistor DRAM Line Memories," IEEE Journal of Solid-State Circuits, Vol. 24, No. 6, pp. 1656-1659 (Dec. 1989)
MA	Amitai, Z., "Burst Mode Memories Improve Cache Design," WESCON/90 Conference Record, pp. 29-32 (Nov. 1990)
MA	Robert J. Lodi et al., "MNOS-BORAM Memory Characteristics," IEEE Journal of Solid-State Circuits, vol. SC-11, No. 5, pp. 622-631 (Oct. 1976)

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